SGS-THOMSON MICROELECTRONICS

M54HC194
M74HC194
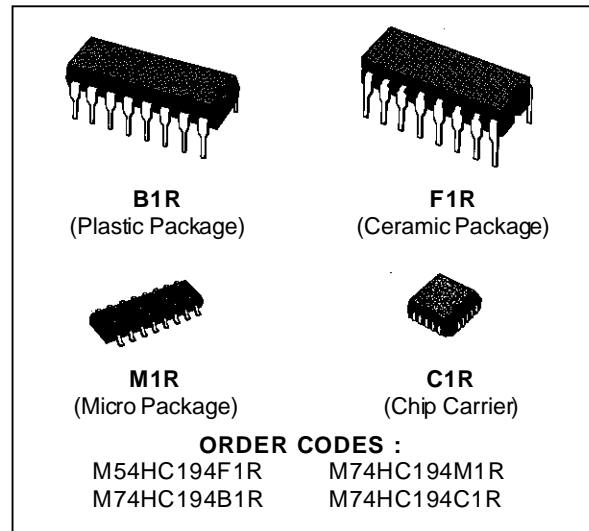
4 BIT PIPO SHIFT REGISTER

- HIGH SPEED
  t_{PD} = 12 ns (TYP.) AT V_{CC} = 5 V
- LOW POWER DISSIPATION
  I_{CC} = 4 μA (MAX.) AT T_A = 25 °C
- OUTPUT DRIVE CAPABILITY
  10 LSTTL LOADS
- SYMMETRICAL OUTPUT IMPEDANCE
  $|I_{OH}| = I_{OL}$ = 4 mA (MIN.)
- BALANCED PROPAGATION DELAYS
  $t_{PLH} = t_{PHL}$
- HIGH NOISE IMMUNITY
  $V_{NIH} = V_{NIL}$ = 28 % V_{CC} (MIN.)
- WIDE OPERATING VOLTAGE RANGE
  V_{CC} (OPR) = 2 V TO 6 V
- PIN AND FUNCTION COMPATIBLE
  WITH 54/74LS194

B1R
(Plastic Package)

F1R
(Ceramic Package)

M1R
(Micro Package)

C1R
(Chip Carrier)

ORDER CODES :
M54HC194F1R   M74HC194M1R
M74HC194B1R   M74HC194C1R

DESCRIPTION

The M54/74HC194 is a high speed CMOS 4 BIT PIPO SHIFT REGISTER fabricated in silicon gate C^{2}MOS technology. It has the same high speed performance of LSTTL combined with true CMOS low power consumption. This SHIFT REGISTER is designed to incorporate virtually all of the features a system designer may want in a shift register. It features parallel inputs, parallel outputs, right shift and left shift serial inputs, clear line. The register has four distinct modes of operation : PARALLEL (broadside) LOAD ; SHIFT RIGHT (in the direction Q_A Q_D); SHIFT LEFT ; INHIBIT CLOCK (do nothing). Synchronous parallel loading is accomplished by applying the four data bits and taking both mode control inputs, S0 and S1 high. The data are loaded into their respective flip-flops and appear at the outputs after the positive transition of the CLOCK input. During loading, serial data flow is inhibited. Shift right is accomplished synchronously with the rising edge of the clock pulse when S0 is high and S1 is low. Serial data for this mode is entered at the SHIFT RIGHT data input. When S0 is low and S1 is high, data shifts left synchronously and new data is entered at the SHIFT LEFT serial input. Clocking of the flip flops is inhibited when both mode control inputs are low. The mode control inputs should be changed only when the CLOCK input is high. All inputs are equipped with protection circuits against static discharge and transient excess voltage.

PIN CONNECTIONS (top view)

NC =
No Internal
Connection
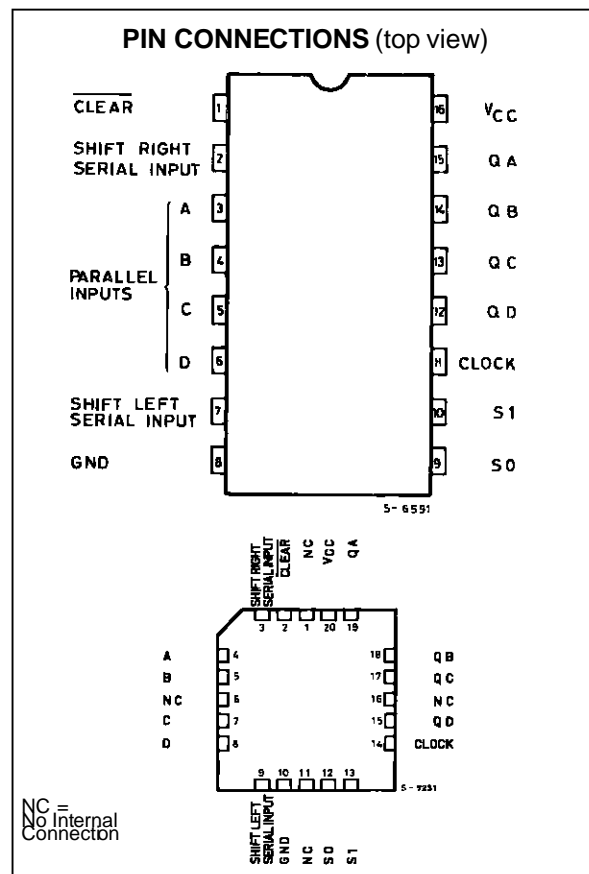
INPUT AND OUTPUT EQUIVALENT CIRCUIT

PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
1	$\overline{\text{CLEAR}}$	Asynchronous Reset Input (Active LOW)
2	SR	Serial Data Input (Shift Right)
3, 4, 5, 6	A to D	Parallel Data Input
7	SL	Serial Data Input (Shift Left)
9, 10	S0, S1	Mode Control Inputs
11	CLOCK	Clock Input (LOW to HIGH Edge-triggered)
15, 14, 13, 12	QA to QD	Paralle Outputs
8	GND	Ground (0V)
16	V_{CC}	Positive Supply Voltage

IEC LOGIC SYMBOL
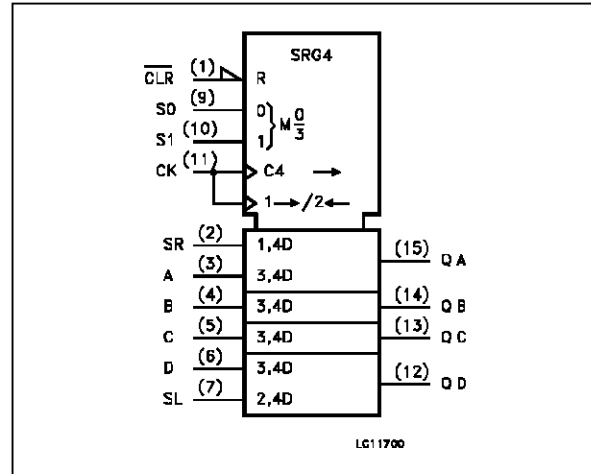
TRUTH TABLE

INPUTS										OUTPUS			
$\overline{\text{CLEAR}}$	MODE		CLOCK	SERIAL		PARALLEL				QA	QB	QC	QD
	S1	S0		LEFT	RIGHT	A	B	C	D				
L	X	X	X	X	X	X	X	X	X	L	L	L	L
H	X	X	⌐	X	X	X	X	X	X	QA0	QB0	QC0	QD0
H	H	H	⌐	X	X	a	b	c	d	a	b	c	d
H	L	H	⌐	X	H	X	X	X	X	H	QAn	QBn	QCn
H	L	H	⌐	X	L	X	X	X	X	L	QAn	QBn	QCn
H	H	L	⌐	H	X	X	X	X	X	QBn	QCn	QDn	H
H	H	L	⌐	L	X	X	X	X	X	QBn	QCn	QDn	L
H	L	L	X	X	X	X	X	X	X	QA0	QB0	QC0	QD0

X: Don't Care : Don't Care
a ~ d : The level of steady state input voltage at input A ~ D respactively
QA0 ~ QD0 : No change
QAn ~ QDn : The level of QA, QB, QC, respectively, before the mst recent positive transition of the clock.

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LOGIC DIAGRAM
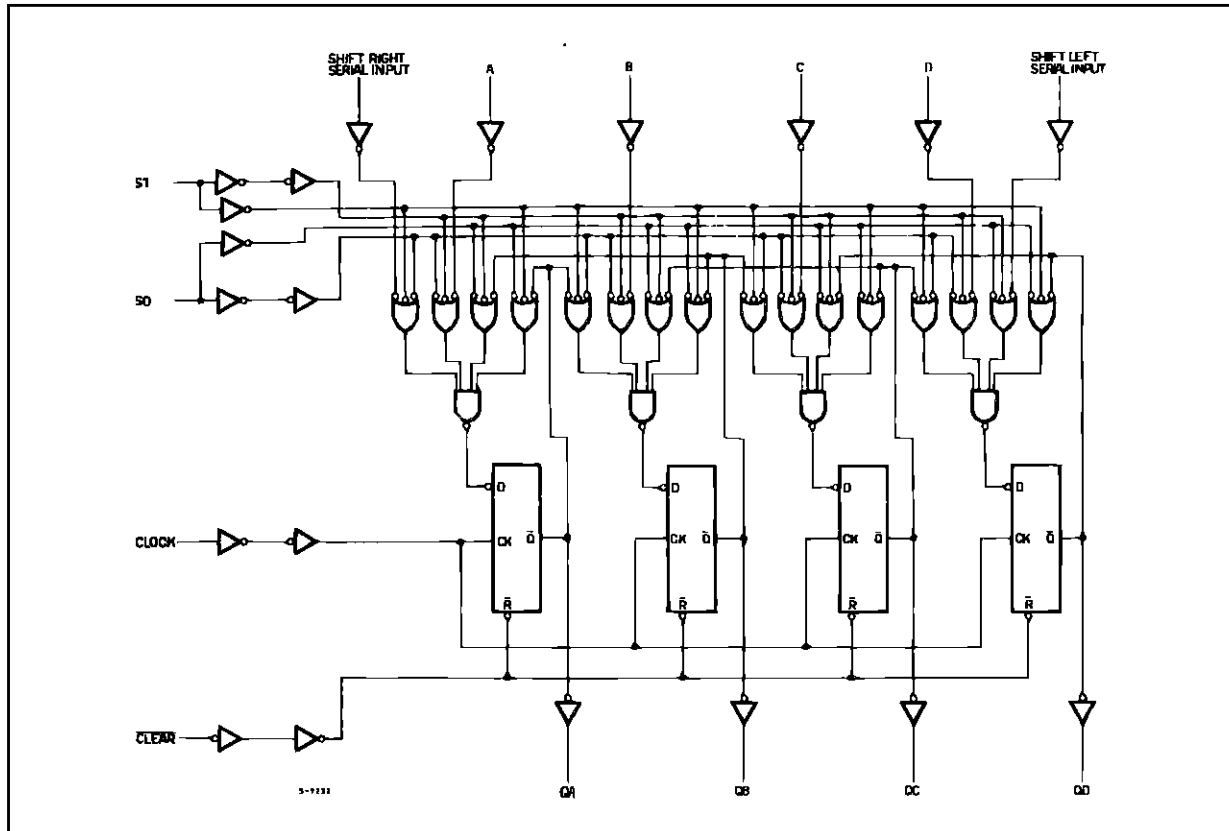
TIMING CHART
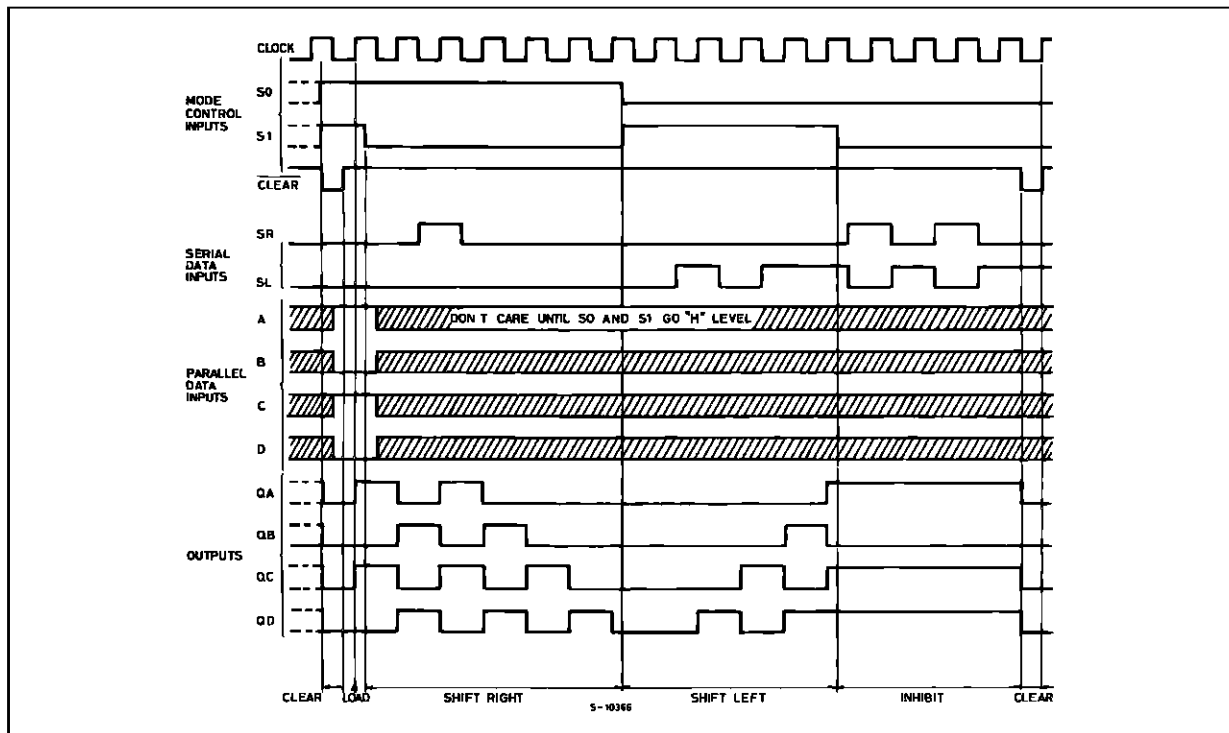
ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	-0.5 to +7	V
V_I	DC Input Voltage	-0.5 to V_{CC} + 0.5	V
V_O	DC Output Voltage	-0.5 to V_{CC} + 0.5	V
I_{IK}	DC Input Diode Current	$\pm$ 20	mA
I_{OK}	DC Output Diode Current	$\pm$ 20	mA
I_O	DC Output Source Sink Current Per Output Pin	$\pm$ 25	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current	$\pm$ 50	mA
P_D	Power Dissipation	500 (*)	mW
T_{stg}	Storage Temperature	-65 to +150	^oC
T_L	Lead Temperature (10 sec)	300	^oC

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.
(*) 500 mW: $\cong$ 65 ^oC derate to 300 mW by 10mW/^oC: 65 ^oC to 85 ^oC

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Value	Unit
V_{CC}	Supply Voltage		2 to 6	V
V_I	Input Voltage		0 to V_{CC}	V
V_O	Output Voltage		0 to V_{CC}	V
T_{op}	Operating Temperature: **M54HC** Series		-55 to +125	^oC
	M74HC Series		-40 to +85	^oC
t_r, t_f	Input Rise and Fall Time	V_{CC} = 2 V	0 to 1000	ns
		V_{CC} = 4.5 V	0 to 500	
		V_{CC} = 6 V	0 to 400	

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DC SPECIFICATIONS

Symbol	Parameter	Test Conditions V_{CC} (V)			$T_A = 25\ ^oC$ 54HC and 74HC			-40 to 85 ^oC 74HC		-55 to 125 ^oC 54HC		Unit
					Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
V_{IH}	High Level Input Voltage	2.0			1.5			1.5		1.5		V
		4.5			3.15			3.15		3.15		
		6.0			4.2			4.2		4.2		
V_{IL}	Low Level Input Voltage	2.0					0.5		0.5		0.5	V
		4.5					1.35		1.35		1.35	
		6.0					1.8		1.8		1.8	
V_{OH}	High Level Output Voltage	2.0	$V_I =$ V_{IH} or V_{IL}	I_O=-20 µA	1.9	2.0		1.9		1.9		V
		4.5			4.4	4.5		4.4		4.4		
		6.0			5.9	6.0		5.9		5.9		
		4.5		I_O=-4.0 mA	4.18	4.31		4.13		4.10		
		6.0		I_O=-5.2 mA	5.68	5.8		5.63		5.60		
V_{OL}	Low Level Output Voltage	2.0	$V_I =$ V_{IH} or V_{IL}	I_O= 20 µA		0.0	0.1		0.1		0.1	V
		4.5				0.0	0.1		0.1		0.1	
		6.0				0.0	0.1		0.1		0.1	
		4.5		I_O= 4.0 mA		0.17	0.26		0.33		0.40	
		6.0		I_O= 5.2 mA		0.18	0.26		0.33		0.40	
I_I	Input Leakage Current	6.0	$V_I = V_{CC}$ or GND				±0.1		±1		±1	µA
I_{CC}	Quiescent Supply Current	6.0	$V_I = V_{CC}$ or GND				4		40		80	µA

AC ELECTRICAL CHARACTERISTICS $(C_L = 50\ pF$, Input $t_r = t_f = 6\ ns)$

Symbol	Parameter	Test Conditions V_{CC} (V)		Value $T_A = 25\ ^oC$ 54HC and 74HC			-40 to 85 ^oC 74HC		-55 to 125 ^oC 54HC		Unit
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
t_{TLH} t_{THL}	Output Transition Time	2.0			30	75		95		115	ns
		4.5			8	15		19		23	
		6.0			7	13		16		20	
t_{PLH} t_{PHL}	Propagation Delay Time (CLOCK - Q)	2.0			48	115		145		175	ns
		4.5			15	23		29		35	
		6.0			13	20		25		30	
t_{PHL}	Propagation Delay Time (CLEAR - Q)	2.0			52	125		155		190	ns
		4.5			17	25		31		38	
		6.0			15	21		26		32	
f_{MAX}	Maximum Clock Frequency	2.0		6.2	13		5.0		4.2		MHz
		4.5		31	50		25		21		
		6.0		37	59		30		25		
$t_{W(H)}$ $t_{W(L)}$	Minimum Pulse Width (CLOCK)	2.0			20	75		95		110	ns
		4.5			5	15		19		22	
		6.0			4	13		16		19	
$t_{W(L)}$	Minimum Pulse Width (CLEAR)	2.0			24	75		95		110	ns
		4.5			6	15		19		22	
		6.0			5	13		16		19	
t_s	Minimum Set-up Time (SI, PI - CK)	2.0			20	75		95		110	ns
		4.5			5	15		19		22	
		6.0			4	13		16		20	
t_s	Minimum Set-up Time (S0, S1 - CK)	2.0			28	75		95		110	ns
		4.5			7	15		19		23	
		6.0			6	13		16		20	
t_h	Minimum Hold Time	2.0				0		0		0	ns
		4.5				0		0		0	
		6.0				0		0		0	
t_{REM}	Minimum Removal Time	2.0				5		5		5	ns
		4.5				5		5		5	
		6.0				5		5		5	
C_{IN}	Input Capacitance				5	10		10		10	pF
C_{PD} (*)	Power Dissipation Capacitance				85						pF

(*) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operting current can be obtained by the following equation. $I_{CC}(opr) = C_{PD} \bullet V_{CC} \bullet f_{IN} + I_{CC}$

SWITCHING CHARACTERISTICS TEST WAVEFORM

TEST CIRCUIT I_{CC} (Opr.)

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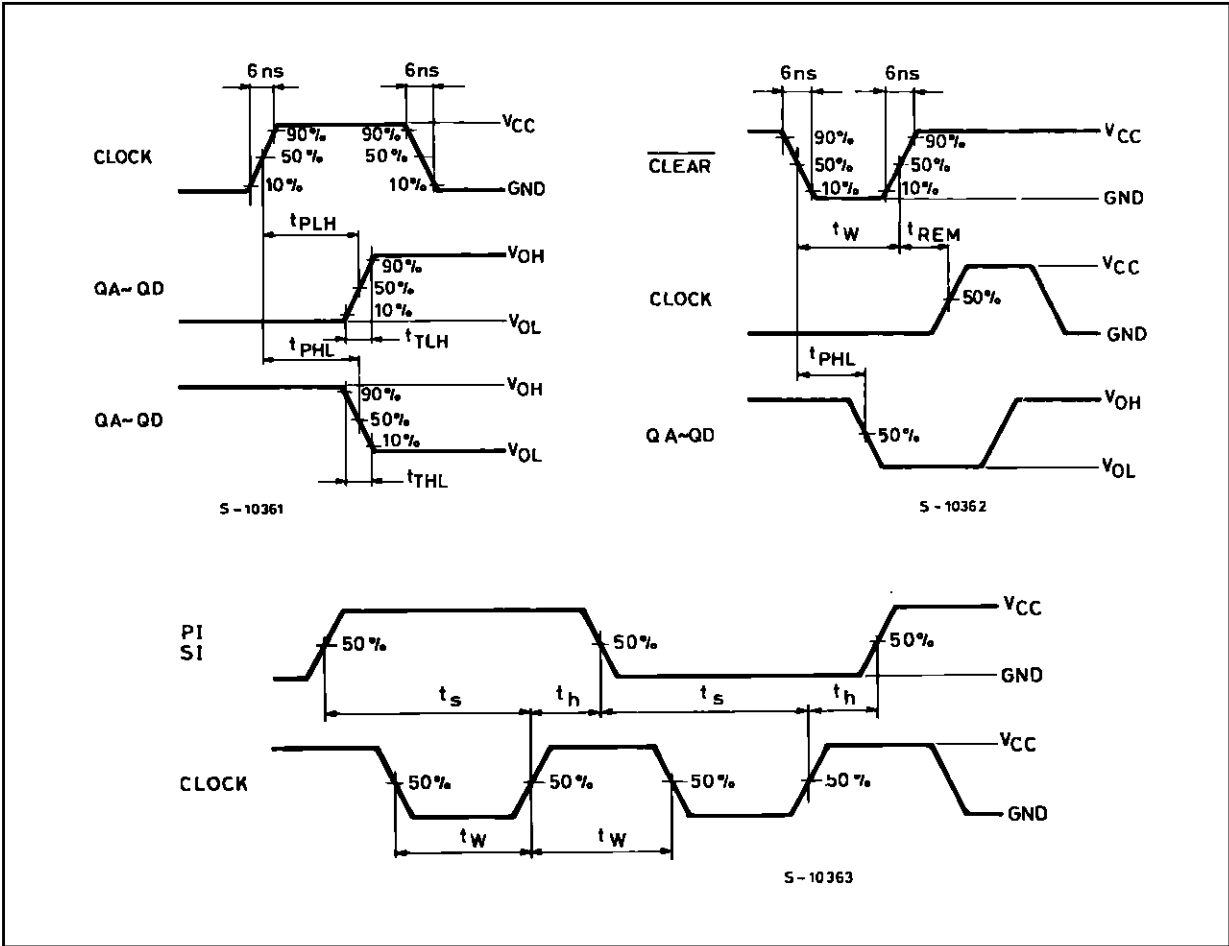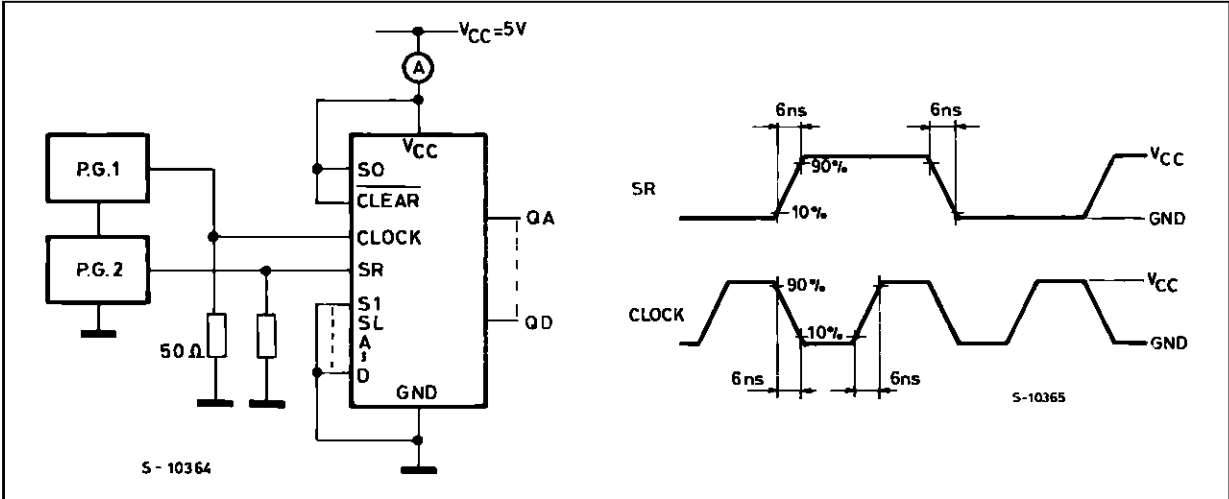
Plastic DIP16 (0.25) MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050

P001C

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Ceramic DIP16/1 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			20			0.787
B			7			0.276
D		3.3			0.130	
E	0.38			0.015		
e3		17.78			0.700	
F	2.29		2.79	0.090		0.110
G	0.4		0.55	0.016		0.022
H	1.17		1.52	0.046		0.060
L	0.22		0.31	0.009		0.012
M	0.51		1.27	0.020		0.050
N			10.3			0.406
P	7.8		8.05	0.307		0.317
Q			5.08			0.200

P053D

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SO16 (Narrow) MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.2	0.004		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45° (typ.)					
D	9.8		10	0.385		0.393
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		8.89			0.350	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.62			0.024
S	8° (max.)					

P013H

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PLCC20 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	9.78		10.03	0.385		0.395
B	8.89		9.04	0.350		0.356
D	4.2		4.57	0.165		0.180
d1		2.54			0.100	
d2		0.56			0.022	
E	7.37		8.38	0.290		0.330
e		1.27			0.050	
e3		5.08			0.200	
F		0.38			0.015	
G			0.101			0.004
M		1.27			0.050	
M1		1.14			0.045	

G (Seating Plane Coplanarity)

P027A

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